

**4N22****4N23****JAN, JANTX, JANTXV, SINGLE CHANNEL OPTOCOUPPLERS****4N24****Mii****OPTOELECTRONIC PRODUCTS  
DIVISION****Features:**

- Overall current gain...1.5 typical (4N24)
- Base lead provided for conventional transistor biasing
- Rugged package
- High gain, high voltage transistor
- +1kV electrical isolation

**Applications:**

- Eliminate ground loops
- Level shifting
- Line receiver
- Switching power supplies
- Motor control

**DESCRIPTION**

Gallium Aluminum Arsenide (GaAlAs) infrared LED and a high gain N-P-N silicon phototransistor packaged in a hermetically sealed metal case. The **4N22**, **4N23** and **4N24**'s can be tested to customer specifications, as well as to MIL-PRF-19500 JAN, JANS, JANTX and JANTXV quality levels.

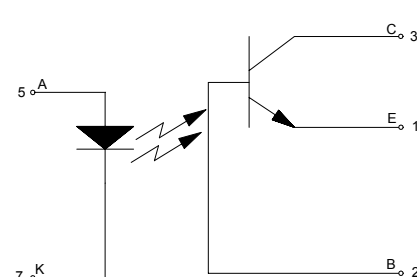
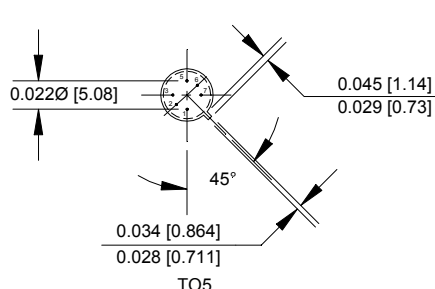
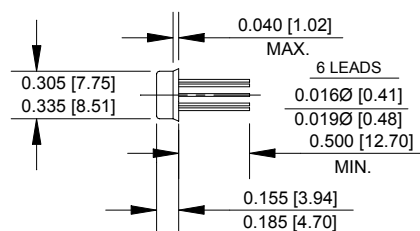
**\*ABSOLUTE MAXIMUM RATINGS**

|  |                 |
|--|-----------------|
| Input to Output Voltage.....   | ±1kV            |
| Emitter-Collector Voltage.....   | 4V              |
| Collector-Emitter Voltage ( $V_{CEO}$ , $I_F = 0$ ).....   | 35V             |
| Collector-Base Voltage ( $V_{CEO}$ , $I_F = 0$ ).....  | 35V             |
| Reverse Input Voltage .....  | 2V              |
| Input Diode Continuous Forward Current at (or below) 65°C Free-Air Temperature (see note 1) .....  | 40mA            |
| Peak Forward Input Current (Value applies for $t_w \leq 1\mu s$ PRR < 300 pps) .....               | 1A              |
| Continuous Collector Current .....   | 50mA            |
| Continuous Transistor Power Dissipation at (or below) 25°C Free-Air Temperature (see Note 2) ..... | 300mW           |
| Storage Temperature.....   | -65°C to +125°C |
| Operating Free-Air Temperature Range .....   | -55°C to +125°C |
| Lead Solder Temperature (1/16" (1.6mm) from case for 10 seconds).....                              | 240°C           |

**Notes:**

1. Derate linearly to 125°C free-air temperature at the rate of 0.67 mW/°C above 65°C.
2. Derate linearly to 125°C free-air temperature at the rate of 5 mW/°C above 65°C.

\* JEDEC registered data

**Package Dimensions****Schematic Diagram**

NOTE: ALL LINEAR DIMENSIONS ARE IN INCHES (MILLIMETERS)

**\*ELECTRICAL CHARACTERISTICS INPUT LED**  $T_A = 25^\circ\text{C}$  Unless otherwise specified

| PARAMETER                          | SYMBOL | MIN | MAX | UNITS         | TEST CONDITIONS     | NOTE |
|------------------------------------|--------|-----|-----|---------------|---------------------|------|
| Input Diode Static Reverse Current | $I_R$  |     | 100 | $\mu\text{A}$ | $V_R = 2\text{V}$   |      |
| Input Diode Static Forward Voltage | $V_F$  | 1   | 1.5 | V             | $I_F = 10\text{mA}$ |      |
| -55°C                              |        | 0.8 | 1.3 |               |                     |      |
| +25°C                              |        | 0.7 | 1.2 |               |                     |      |
| +125°C                             |        |     |     |               |                     |      |

**\*OUTPUT TRANSISTOR**  $T_A = 25^\circ\text{C}$  Unless otherwise specified

| PARAMETER                           | SYMBOL        | MIN | MAX | UNITS | TEST CONDITIONS                                | NOTE |
|-------------------------------------|---------------|-----|-----|-------|--|------|
| Collector-Base Breakdown Voltage    | $V_{(BR)CBO}$ | 35  |     | V     | $I_C = 100\mu\text{A}$ , $I_B = 0$ , $I_F = 0$ |      |
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | 35  |     | V     | $I_C = 1\text{mA}$ , $I_B = 0$ , $I_F = 0$     |      |
| Emitter-Base Breakdown Voltage      | $V_{(BR)EBO}$ | 4   |     | V     | $I_C = 0$ , $I_E = 100\mu\text{A}$ , $I_F = 0$ |      |

**\*COUPLED CHARACTERISTICS**  $T_A = 25^\circ\text{C}$  Unless otherwise specified

| PARAMETER                            | SYMBOL        | MIN       | MAX | UNITS         | TEST CONDITIONS   | NOTE |
|--------------------------------------|---------------|-----------|-----|---------------|---|------|
| On State Collector Current           | $I_{C(ON)}$   | 0.15      |     | mA            | $V_{CE} = 5\text{V}$ , $I_B = 0$ , $I_F = 2\text{mA}$           |      |
| 4N22                                 |               | 0.2       |     |               |   |      |
| 4N23                                 |               | 0.4       |     |               |   |      |
| 4N24                                 |               |           |     |               |   |      |
| On State Collector Current           | $I_{C(ON)}$   | 2.5       |     | mA            | $V_{CE} = 5\text{V}$ , $I_B = 0$ , $I_F = 10\text{mA}$          |      |
| 4N22                                 |               | 6         |     |               |   |      |
| 4N23                                 |               | 10        |     |               |   |      |
| 4N24                                 |               |           |     |               |   |      |
| On State Collector Current           | $I_{C(ON)}$   | 1         |     | mA            | $V_{CE} = 5\text{V}$ , $I_B = 0$ , $I_F = 10\text{mA}$          |      |
| -55°C                                |               | 2.5       |     |               |   |      |
| 4N22                                 |               | 4         |     |               |   |      |
| 4N23                                 |               |           |     |               |   |      |
| 4N24                                 |               |           |     |               |   |      |
| On State Collector Current           | $I_{C(ON)}$   | 1         |     | mA            | $V_{CE} = 5\text{V}$ , $I_B = 0$ , $I_F = 10\text{mA}$          |      |
| +100°C                               |               | 2.5       |     |               |   |      |
| 4N22                                 |               | 4         |     |               |   |      |
| 4N23                                 |               |           |     |               |   |      |
| 4N24                                 |               |           |     |               |   |      |
| Off State Collector Current +25°C    | $I_{C(OFF)}$  |           | 100 | nA            | $V_{CE} = 20\text{V}$ , $I_B = 0$ , $I_F = 0\text{mA}$          |      |
| Off State Collector Current +100°C   | $I_{C(OFF)}$  |           | 100 | $\mu\text{A}$ | $V_{CE} = 20\text{V}$ , $I_B = 0$ , $I_F = 0\text{mA}$          |      |
| Collector-Emitter Saturation Voltage | $V_{CE(SAT)}$ |           | 0.3 | V             | $I_C = 2.5\text{mA}$ , $I_B = 0$ , $I_F = 20\text{mA}$          |      |
| 4N22                                 |               |           | 0.3 | V             | $I_C = 5\text{mA}$ , $I_B = 0$ , $I_F = 20\text{mA}$            |      |
| 4N23                                 |               |           | 0.3 | V             | $I_C = 10\text{mA}$ , $I_B = 0$ , $I_F = 20\text{mA}$           |      |
| 4N24                                 |               |           | 0.3 | V             |   |      |
| Input to Output Resistance           | $R_{I-O}$     | $10^{11}$ |     |               | $V_{IN-OUT} = 1\text{kV}$                                       | 1    |
| Input to Output Capacitance          | $C_{I-O}$     |           | 5   | pF            | $F = 1\text{MHz}$ , $V_{IN-OUT} = 1\text{kV}$                   | 1    |
| Rise Time                            | $t_r$         |           | 15  | $\mu\text{s}$ | $V_{CC} = 10\text{V}$ , $I_F = 10\text{mA}$ , $R_L = 100\Omega$ |      |
| 4N22                                 |               |           | 15  | $\mu\text{s}$ |   |      |
| 4N23                                 |               |           | 20  | $\mu\text{s}$ |   |      |
| 4N24                                 |               |           |     |               |   |      |
| Fall Time                            | $t_f$         |           | 15  | $\mu\text{s}$ | $V_{CC} = 10\text{V}$ , $I_F = 10\text{mA}$ , $R_L = 100\Omega$ |      |
| 4N22                                 |               |           | 15  | $\mu\text{s}$ |   |      |
| 4N23                                 |               |           | 20  | $\mu\text{s}$ |   |      |
| 4N24                                 |               |           |     |               |   |      |

**NOTES:**

- These parameters are measured between all phototransistor leads shorted together and with both input diode leads shorted together.

**RECOMMENDED OPERATING CONDITIONS:**

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| PARAMETER                 | SYMBOL          | MIN | MAX | UNITS |
|---------------------------|-----------------|-----|-----|-------|
| Input Current, Low Level  | I <sub>FL</sub> | 0   | 1   | μA    |
| Input Current, High Level | I <sub>FH</sub> | 2   | 10  | mA    |
| Supply Voltage            | V <sub>CE</sub> | 5   | 10  | V     |

#### SELECTION GUIDE

| PART NUMBER | PART DESCRIPTION                         |
|-------------|--|
| JAN4N22     | 4N22 Optocoupler, JAN Screening level    |
| JAN4N23     | 4N23 Optocoupler, JAN Screening level    |
| JAN4N24     | 4N24 Optocoupler, JAN Screening level    |
| JANTX4N22   | 4N22 Optocoupler, JANTX Screening level  |
| JANTX4N23   | 4N23 Optocoupler, JANTX Screening level  |
| JANTX4N24   | 4N24 Optocoupler, JANTX Screening level  |
| JANTXV4N22  | 4N22 Optocoupler, JANTXV Screening level |
| JANTXV4N23  | 4N23 Optocoupler, JANTXV Screening level |
| JANTXV4N24  | 4N24 Optocoupler, JANTXV Screening level |

\* JEDEC registered data

## THESE CHARTS APPLY TO:

4N22, 4N23, and 4N24

JAN, JANTX, JANTXV, OPTOCOUPLERS Page

4N22A, 4N23A, and 4N24A

JAN, JANTX, JANTXV, OPTOCOUPLERS Page

4N22U, 4N23U, and 4N24U

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